

PATENT APPLICATION
IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q80822

Masatomo SHIBATA

Allowed: June 21, 2007

Appln. No.: 10/813,176

Group Art Unit: 2813

Confirmation No.: 4446

Examiner: Jennifer M. Dolan

Filed: March 31, 2004

For: III-V NITRIDE SEMICONDUCTOR SUBSTRATE AND ITS PRODUCTION METHOD

AMENDMENT UNDER 37 C.F.R. §1.312

MAIL STOP ISSUE FEE

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Sir:

Pursuant to the provisions of 37 C.F.R. §1.312, please amend the above-identified application as follows on the accompanying pages.

TABLE OF CONTENTS

AMENDMENTS TO THE CLAIMS	2
REMARKS	5